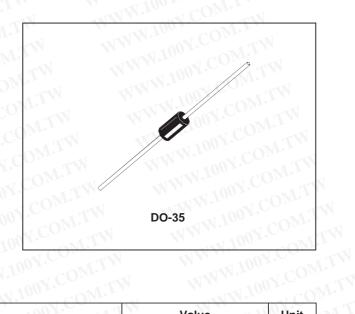


BAT42 BAT43

SMALL SIGNAL SCHOTTKY DIODES



DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage fast switching.

These devices have integrated protection against excessive voltage such as electrostatic dis-

ABSOLUTE RATINGS (limiting values)

V _{RRM}			Value	Unit
- IXIXIVI	Repetitive Peak Reverse Voltage		30	1 100V
l _F	Forward Continuous Current	T _a = 25°C	200	mA
I _{FRM}	Repetitive Peak Fordware Current	$t_p \le 1s$ $\delta \le 0.5$	500	mA
I _{FSM}	Surge non Repetitive Forward Current*	t _p = 10ms	M.T. 4	A
P _{tot}	Power Dissipation*	T _I = 65 °C	200	mW
T _{stg} T _j	Storage and Junction Temperature Range		- 65 to +150 - 65 to +125	°C °C
TL	Maximum Temperature for Soldering during Case	230	°C	

THERMAL RESISTANCE

Symbol	MMM.IG	Test Conditions	WWW.	Value	Unit
R _{th(j-a)}	Junction-ambient*	TOON.COM.	WWW.	300	°C/W

^{*} On infinite heatsink with 4mm lead length WWW.100Y.COM.TW WWW.100Y.COM.TW

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Http://www.100y.com.tw

M. 100 Y. CO. **ELECTRICAL CHARACTERISTICS**

STATIC CHARACTERISTICS

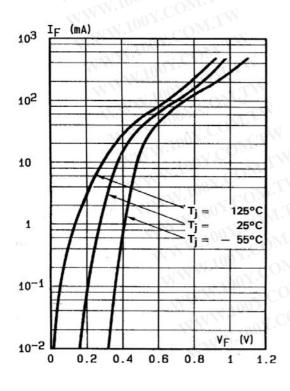
Symbol	N W	Test Conditions	TW W	Min.	Тур.	Max.	Unit
V_{BR}	Tj = 25°C	$I_R = 100 \mu A$	W W	30	ON.CON	WT	V
V _F *	T _j = 25°C	I _F = 200mA	All Types	MM'II	ON.CO	1	V
	T _j = 25°C	I _F = 10mA	BAT 42	WW.	CO CO	0.4	
	T _j = 25°C	I _F = 50mA	OM.T.	NV TANIN	700 r.	0.65	u.i
	$T_j = 25^{\circ}C$	$I_F = 2mA$	BAT 43	0.26	N.100 J.	0.33	
OOY.Co	T _j = 25°C	I _F = 15mA	-oM.TW	11 11	W.1007	0.45	
I _R *	T _j = 25°C	WW VI 100Y	$V_R = 25V$	WW	100	0.5	μА
	T _i = 100°ÉC	MAM.		W	100	100	WT

DYNAMIC CHARACTERISTICS

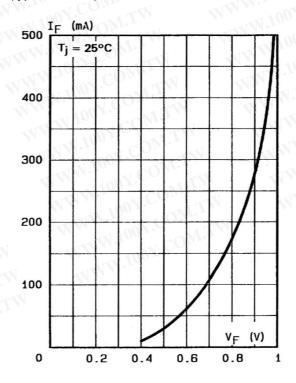
Symbol	Test Conditions	Min.	Typ.	Max.	Unit
C	$T_j = 25^{\circ}C$ $V_R = 1V$ $f = 1MHz$	N	7	7001.	pF
trr	$T_J = 25$ °C $I_F = 10$ mA $I_R = 10$ mA $I_{rr} = 1$ mA $R_L = 100\Omega$		WW	5	ns
h.	$T_i = 25^{\circ}C$ $R_L = 15K\Omega$ $C_L = 300pF$ $f = 45MHz$ $V_i = 2V$	80	- 111		%

^{*} Pulse test: $t_p \le 300 \mu s$ $\delta < 2\%$.

Fig. 1: Forward current versus forward voltage at different temperatures (typical values).



WW.100Y.COM.TW WWW.100Y.COM.TW Fig. 2: Forward current versus forward voltage (typical values).



NW.100Y.COM. Fig. 3: Reverse current versus junction temperature (typical values).

V.100Y.COM.TW

W.100Y.COM.TW

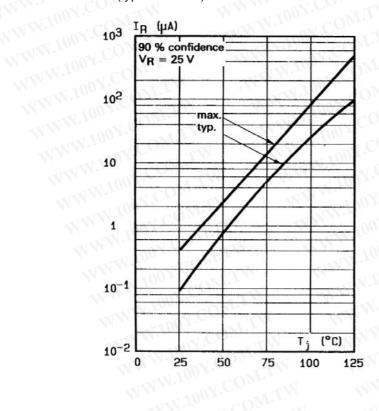


Fig. 4: Reverse current versus continuous reverse voltage.

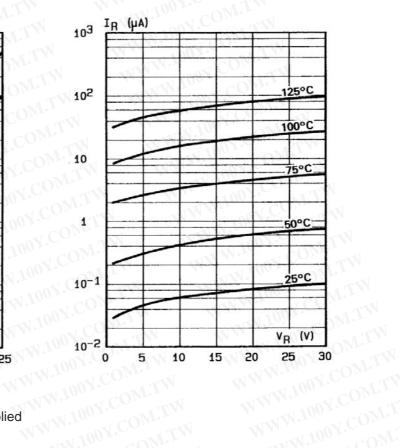
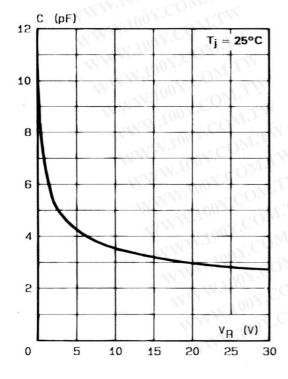
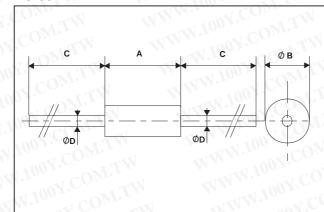


Fig. 5: Capacitance C versus reverse applied voltage V_R (typical values).



PACKAGE MECHANICAL DATA

DO-35



REF.	MM.10	DIMEN	ISIONS	
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	3.05	4.50	0.120	0.177
В	1.53	2.00	0.060	0.079
С	28.00	100	1.102	I.TW
D	0.458	0.558	0.018	0.022

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Cooling method: by convection and conduction

Marking: clear. ring at cathods and

Marking: clear, ring at cathode end.

Weight: 0.15g

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